



Micron Technology



Part Number:	MT53D384M32D2DS-046 WT ES:E
Manufacturer/Brand:	Micron Technology
Product description	IC DRAM 12G 2133MHZ
Datasheets:	
RoHs Status	 Lead free / RoHS Compliant
Ship From	Hong Kong
Shipment Way	DHL/Fedex/TNT/UPS/EMS

REQUEST FOR QUOTATION

Image may be representation. See specifications for product details.

Specifications of MT53D384M32D2DS-046 WT ES:E

PART NUMBER	MT53D384M32D2DS-046 WT ES:E
MANUFACTURER	Micron Technology
DESCRIPTION	IC DRAM 12G 2133MHZ
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DATA SHEET	
WRITE CYCLE TIME - WORD, PAGE	-
VOLTAGE - SUPPLY	1.1V
TECHNOLOGY	SDRAM - Mobile LPDDR4
SERIES	-
OTHER NAMES	MT53D384M32D2DS-046 WT ES:E-ND MT53D384M32D2DS-046WTES:E
OPERATING TEMPERATURE	-30°C ~ 85°C (TC)
MOISTURE SENSITIVITY LEVEL (MSL)	3 (168 Hours)
MEMORY TYPE	Volatile
MEMORY SIZE	12Gb (384M x 32)
MEMORY INTERFACE	-
MEMORY FORMAT	DRAM
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DETAILED DESCRIPTION	SDRAM - Mobile LPDDR4 Memory IC 12Gb (384M x 32) 2133MHz
CLOCK FREQUENCY	2133MHz

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